

Rev.E Mar.-2016

WR0<50P ММ Ё QSQ æ Ñ ç s ll 1 Silicon NPN transistor in a TO-92LM Plastic Package.

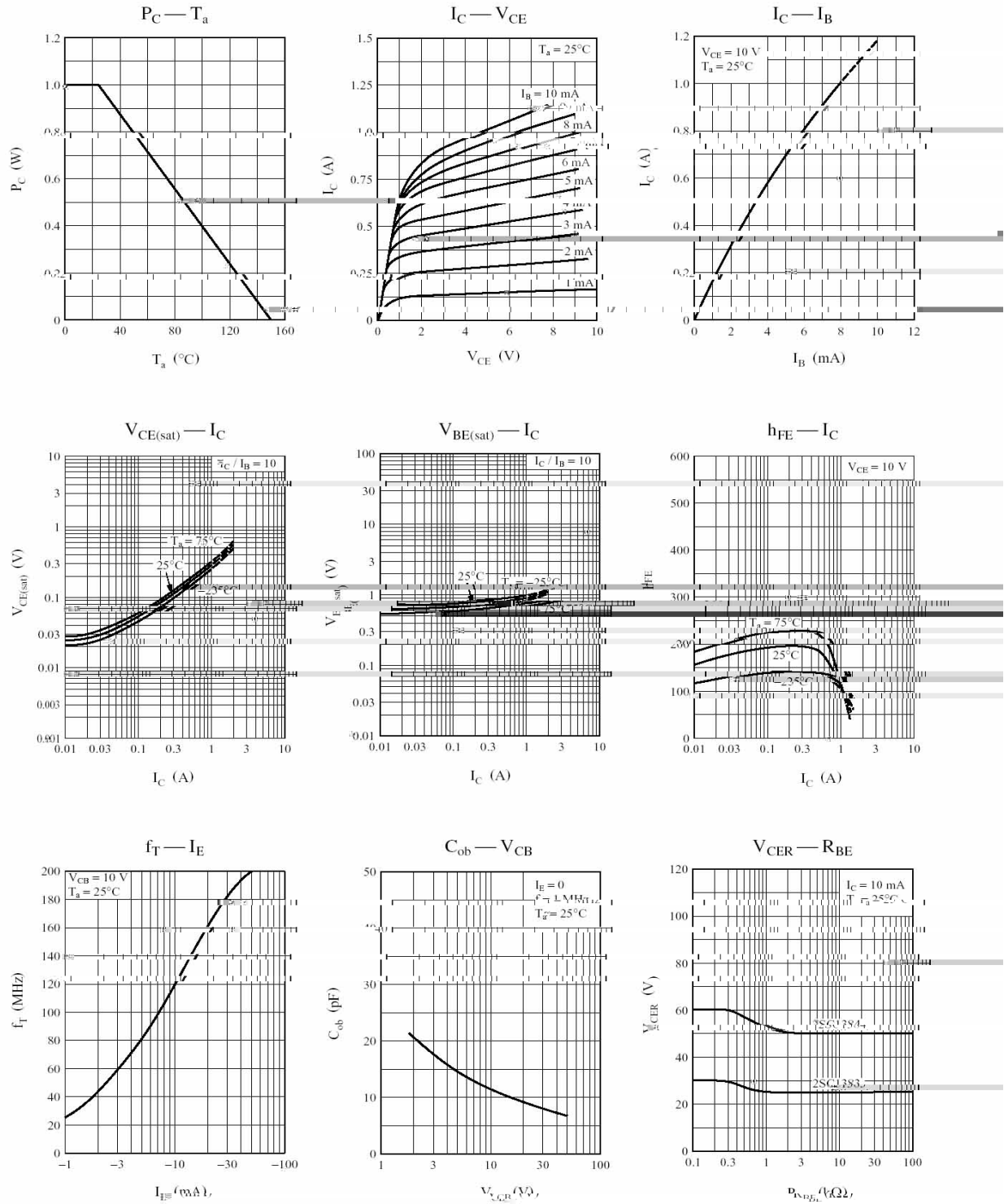
т = э я Н/ 1 ъ 5VD9;6 й ´

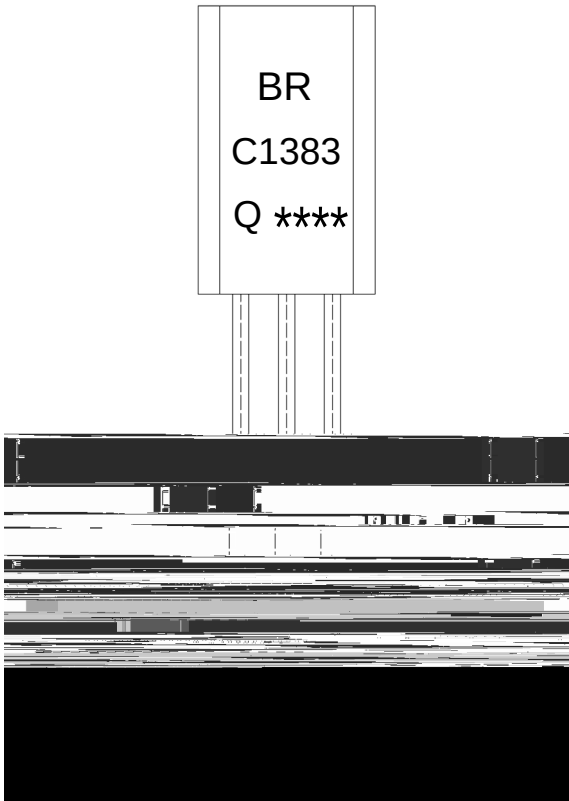
Low $V_{CE(sat)}$, complementary pair with 2SA683.

Low V

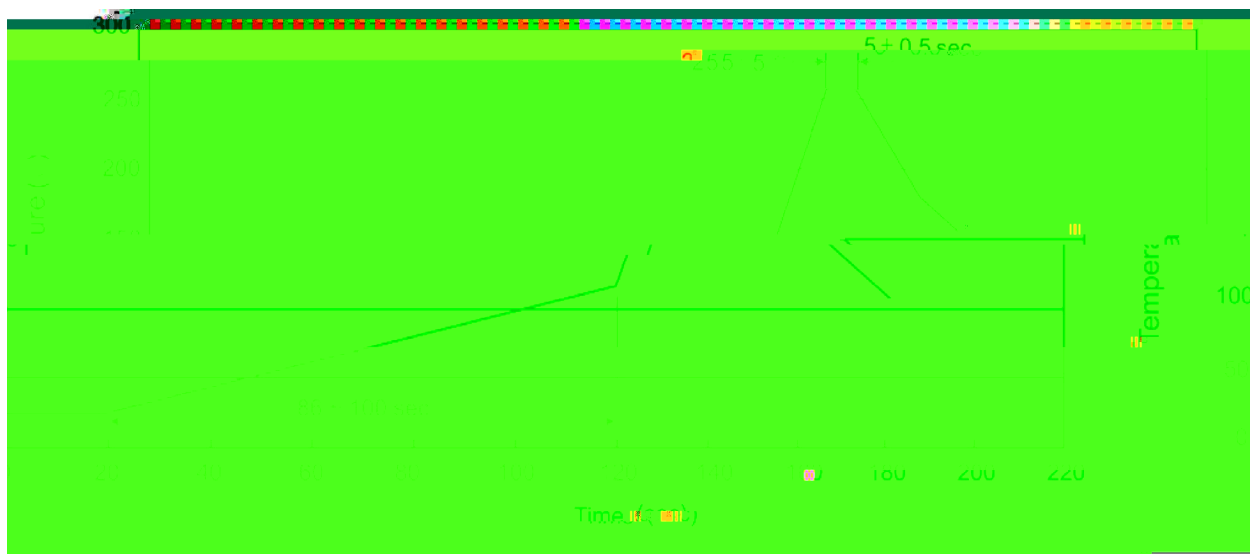
Parameter	Symbol	Rating	Unit
Collector to Base Voltage	V_{CBO}	30	V
Collector to Emitter Voltage	V_{CEO}	25	V
Emitter to Base Voltage	V_{EBO}	5.0	V
Collector Current - Continuous	I_C	1.0	A
Collector Current – Continuous(Pulse)	I_{CP}	1.5	A
Collector Power Dissipation	P_C	1.0	W
Junction Temperature	T_j	150	
Storage Temperature Range	T_{stg}	-55 150	

Parameter	Symbol	Unit	Value
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公司代码	公司代码
EU:	公司代码
F46;6	公司代码
T:	公司代码
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Note:	
BR:	Company Code.
C1383:	Product Type.
Q:	h _{FE} Classifications Symbol
****:	Lot No. Code,code change with Lot No.



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1. ǀ ǂ □ ŷ 25 ª 150 † ǀ ǂ ǂ 60 ª 90sec;
2. Š Œ □ ŷ 255 ° 5 † ǀ ǂ ǂ ǂ ǂ 5 ° 0.5sec;
3. ǀ ǂ ǂ ǂ ǂ ǂ ǂ ǂ ǂ ǂ 2 ª 10 † /sec.

Note:

- 1.Preheating:25~150 † , Time:60~90sec.
- 2.Peak Temp.:255 ° 5 † , Duration:5 ° 0.5sec.
3. Cooling Speed: 2~10 † /sec.

□ ŷ Χ 270 ° 5 †

ǂ ǂ Χ 10 ° 1 sec.

Temp.:270 ° 5 †

Time:10 ° 1 sec

ǂ ǂ ǂ ǂ / BULK

Package Type	Units					Dimension (unit mm3)		
	Units/Bag /	Bags/Inner Box /	Units/Inner Box /	Inner Boxes/Outer Box /	Units/Outer Box /	Bag	Inner Box	Outer Box
TO-92LM	1,000	8	8,000	5	40,000	135×190	237×172×102	560×245×195

ǂ ǂ ǂ ǂ / AMMO

Package Type	Units					Dimension (unit mm3)	
	Units/tape /	Tape/Inner Box /	Rows/Inner Box /	Inner Boxes/Outer Box /	Units/Outer Box /	Inner Box	Outer Box
TO-92LM	2,500	1	100	10	25,000	328×230×42	480×346×235 547×407×268